NSN 5961-01-006-8834

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.205 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 on voltage, forward voltage drop, dc
Current Rating Per Characteristic:
6.00 amperes forward current, average absolute
Power Rating Per Characteristic:
10.0 milliwatts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
85.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0